



ULTRA LOW NOISE, MEDIUM CURRENT

E-PHEMT Transistor

TAV-581+

THE BIG DEAL

- Low Noise Figure, 0.5 dB
- Gain, 17 dB at 2 GHz
- High Output IP3, +31 dBm
- Output Power at 1dB comp., +19 dBm
- Low Current, 30mA
- Wide bandwidth
- External biasing and matching required



Generic photo used for illustration purposes only

CASE STYLE: FG873

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

- Cellular
- ISM
- GSM
- WCDMA
- WiMax
- WLAN
- UNII and HIPERLAN

PRODUCT OVERVIEW

TAV-581+ is an ultra-low noise, high IP3 transistor device, manufactured using E-PHEMT* technology enabling it to work with a single positive supply voltage. It has outstanding Noise Figure, particularly below 2.5 GHz, and when combining this noise figure with high IP3 performance in a single device it makes it an ideal amplifier for demanding base station applications. We offer these units assembled into a complete module, 50Ω in/out, noise matched and fully specified. For more information please see our TAMP family of models on our web site.

SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



Function	Pad Number	Description
Source	2 & 4	Source terminal, normally connected to ground
Gate	3	Gate used for RF input
Drain	1	Drain used for RF output

* Enhancement mode Pseudomorphic High Electron Mobility Transistor.

REV. D
ECO-011337
TAV-581+
220112





E-PHEMT Transistor

ELECTRICAL SPECIFICATIONS AT $T_{AMB}=25^{\circ}\text{C}$, FREQUENCY 0.45 TO 6 GHz

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
DC Specifications						
V_{GS}	Operational Gate Voltage	$V_{DS}=3\text{V}, I_{DS}=30\text{ mA}$	0.28	0.39	0.5	V
V_{TH}	Threshold Voltage	$V_{DS}=3\text{V}, I_{DS}=4\text{ mA}$	0.18	0.26	0.38	V
I_{DSS}	Saturated Drain Current	$V_{DS}=3\text{V}, V_{GS}=0\text{ V}$		1.0	5.0	μA
G_M	Transconductance	$V_{DS}=3\text{V}, G_m=\Delta I_{DS}/\Delta V_{GS}$ $\Delta V_{GS}=V_{GS1}-V_{GS2}$ $V_{GS1}=V_{GS}$ at $I_{DS}=30\text{ mA}$ $V_{GS2}=V_{GS1}+0.05\text{V}$	— — 230 — —	— — 327 — —	— — 560 — —	mS
I_{GSS}	Gate leakage Current	$V_{GD}=V_{GS}=-3\text{V}$			200	μA
RF Specifications, $Z_0=50\text{ Ohms}$ (Figure 1)						
$NF^{(1)}$	Noise Figure	$V_{DS}=3\text{V}, I_{DS}=30\text{ mA}$	$f=0.9\text{ GHz}$	0.4	—	dB
			$f=2.0\text{ GHz}$	0.5	0.9	
			$f=3.9\text{ GHz}$	0.9	—	
			$f=5.8\text{ GHz}$	1.5	—	
			$f=0.9\text{ GHz}$	—	0.4	
Gain	Gain	$V_{DS}=3\text{V}, I_{DS}=30\text{ mA}$	$f=2.0\text{ GHz}$	15.0	17.3	18.5
			$f=3.9\text{ GHz}$	—	12.1	—
			$f=5.8\text{ GHz}$	—	8.8	—
			$f=0.9\text{ GHz}$	—	22.7	—
			$f=2.0\text{ GHz}$	—	17.2	—
OIP3	Output IP3	$V_{DS}=3\text{V}, I_{DS}=30\text{ mA}$	$f=0.9\text{ GHz}$	—	28.3	dBm
			$f=2.0\text{ GHz}$	—	30.3	
			$f=3.9\text{ GHz}$	—	33.0	
			$f=5.8\text{ GHz}$	—	34.7	
			$f=0.9\text{ GHz}$	—	28.1	
$P_{1dB}^{(2)}$	Power output at 1 dB Compression	$V_{DS}=3\text{V}, I_{DS}=30\text{ mA}$	$f=0.9\text{ GHz}$	—	17.8	dBm
			$f=2.0\text{ GHz}$	—	18.3	
			$f=3.9\text{ GHz}$	—	18.8	
			$f=5.8\text{ GHz}$	—	19.1	
			$f=0.9\text{ GHz}$	—	19.4	
		$V_{DS}=4\text{V}, I_{DS}=30\text{ mA}$	$f=0.9\text{ GHz}$	—	20.2	
			$f=2.0\text{ GHz}$	—	—	
			$f=3.9\text{ GHz}$	—	—	
			$f=5.8\text{ GHz}$	—	—	
			$f=0.9\text{ GHz}$	—	—	

MAXIMUM RATINGS⁽³⁾

Symbol	Parameter	Max.	Units
$V_{DS}^{(4)}$	Drain-Source Voltage	5	V
$V_{GS}^{(4)}$	Gate-Source Voltage	-5 to 0.7	V
$V_{GD}^{(4)}$	Gate-Drain Voltage	-5 to 0.7	V
$I_{DS}^{(4)}$	Drain Current	100	mA
I_{GS}	Gate Current	2	mA
P_{DISS}	Total Dissipated Power	550	mW
$P_{IN}^{(5)}$	RF Input Power	17	dBm
T_{CH}	Channel Temperature	150	$^{\circ}\text{C}$
T_{OP}	Operating Temperature	-40 to 85	$^{\circ}\text{C}$
T_{STD}	Storage Temperature	-65 to 150	$^{\circ}\text{C}$
Θ_{JC}	Thermal Resistance	112	$^{\circ}\text{C}/\text{W}$

- (1) Includes testboard loss (measured in Mini-Circuits test board TB-154)
- (2) During Compression, I_{DS} increases to 48mA typ.
- (3) Operation of this device above any one of these parameters may cause permanent damage.
- (4) Assumes DC quiescent conditions.
- (5) I_{GS} is limited to 2 mA during test.



CHARACTERIZATION TEST CIRCUIT

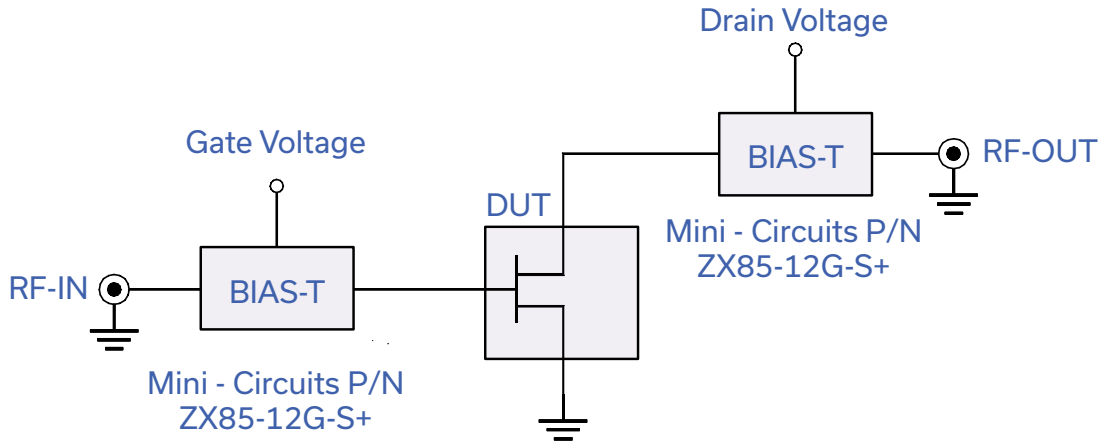


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Test Board TB-154)

Gain, Output power at 1dB compression (P1 dB) and output IP3 (OIP3) are measured using R&S Network Analyzer ZVA-24. Noise Figure measured using Agilent's Noise Figure meter N8975A and noise source N4000A.

Conditions:

1. Drain voltage (with reference to source, VDS)= 3 or 4V as shown.
2. Gate Voltage (with reference to source, VGS) is set to obtain desired Drain-Source current (IDS) as shown in graphs or specification table.
3. Gain: Pin= -25dBm
4. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
5. No external matching components used.

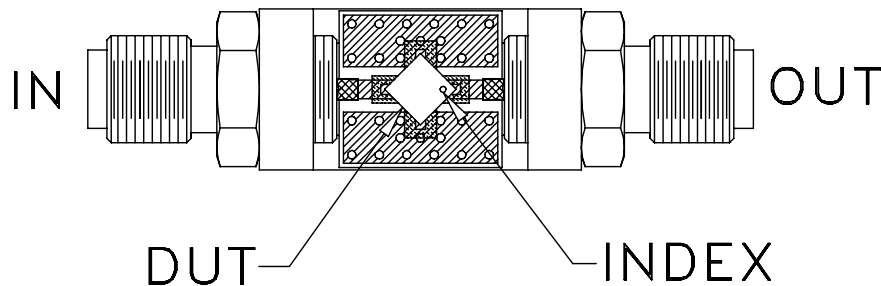
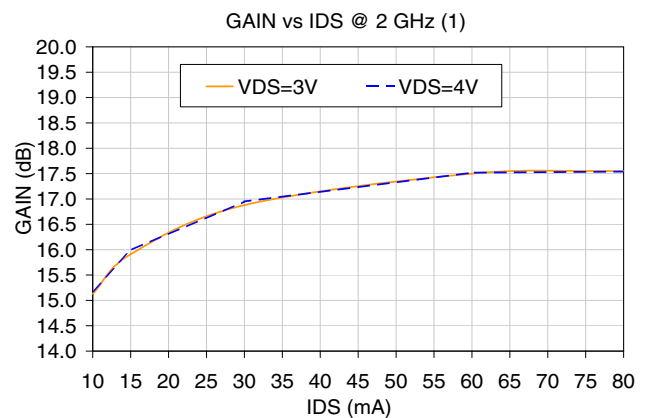
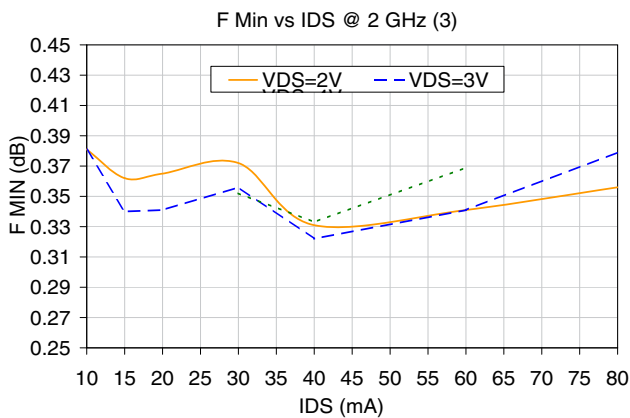
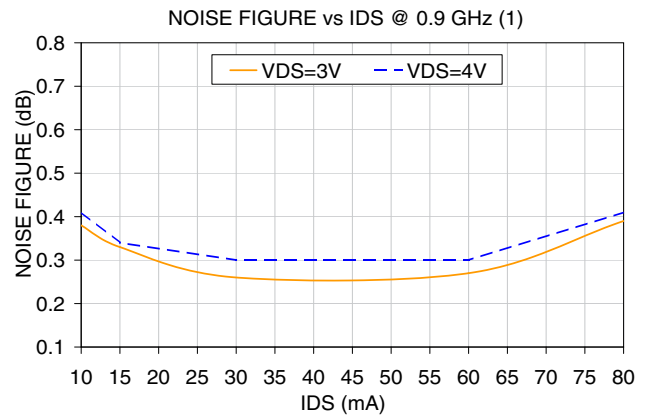
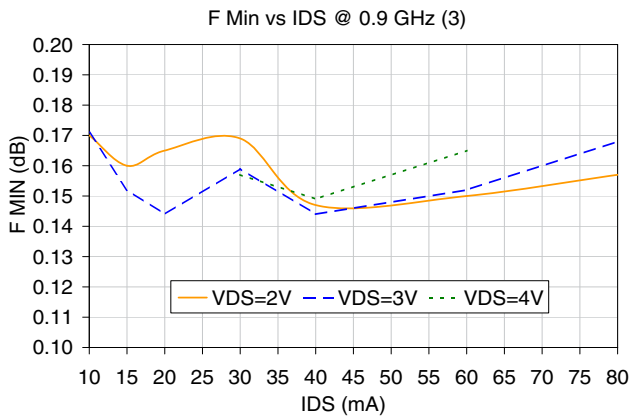
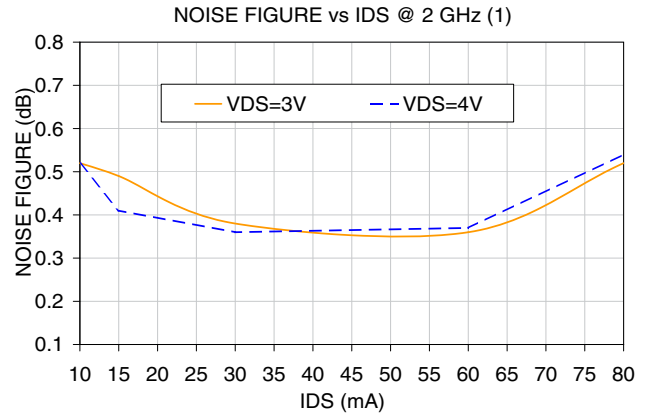
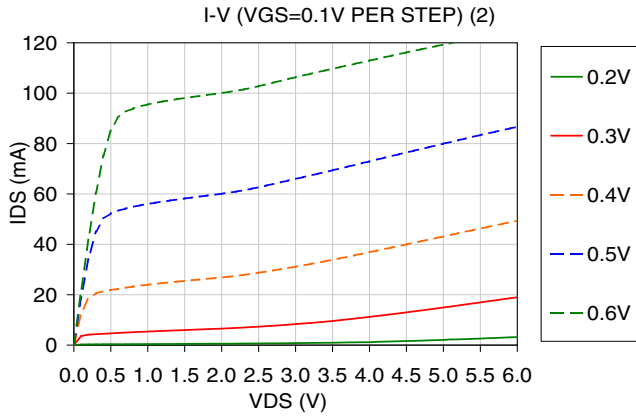


Fig 2. Test Board used for characterization, Mini-Circuits P/N TB-154 (Material: Rogers 4350, Thickness: 0.02")



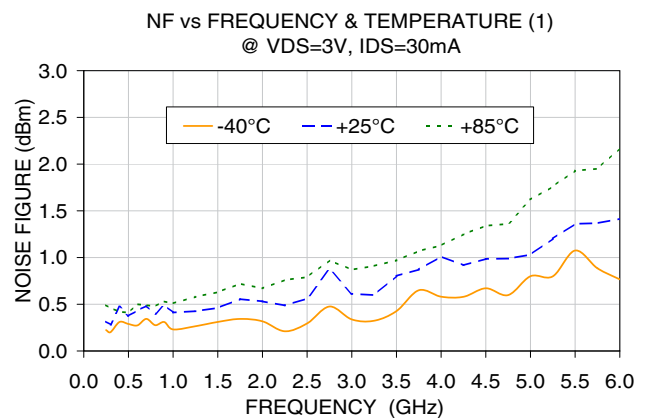
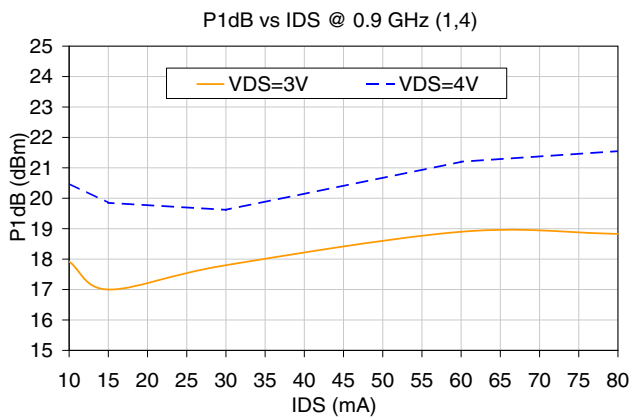
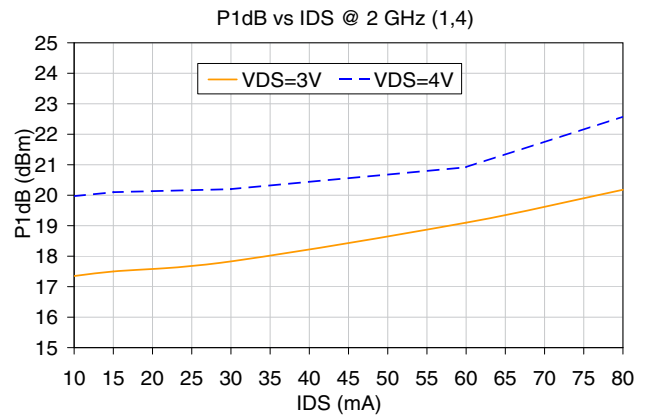
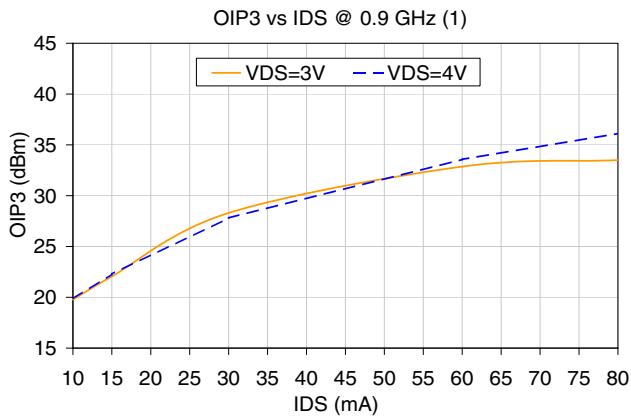
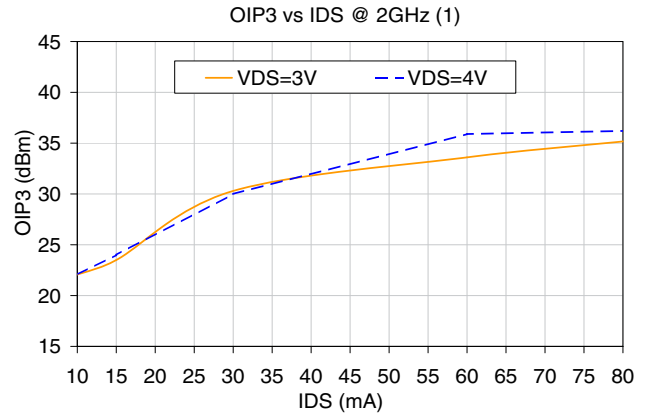
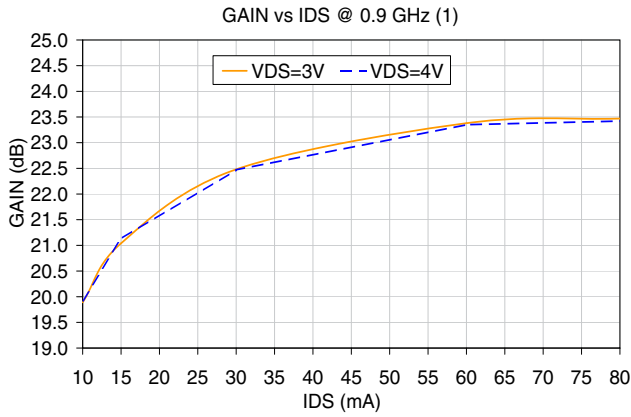
TYPICAL PERFORMANCE CURVES



- (1) Includes test board loss, set-up and conditions per Figure 1.
- (2) Measured using HP4155B semiconductor parameter analyzer.
- (3) F Min is minimum Noise Figure.
- (4) Drain current was allowed to increase during compression measurement.



TYPICAL PERFORMANCE CURVES

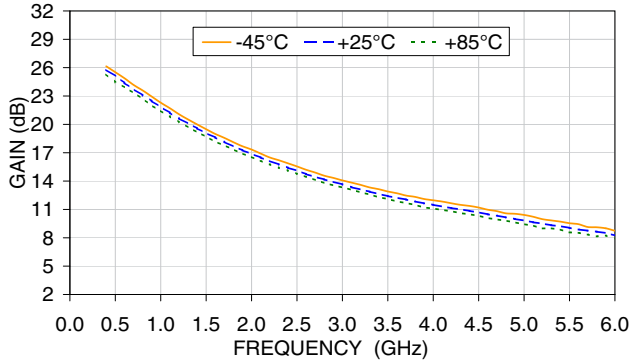


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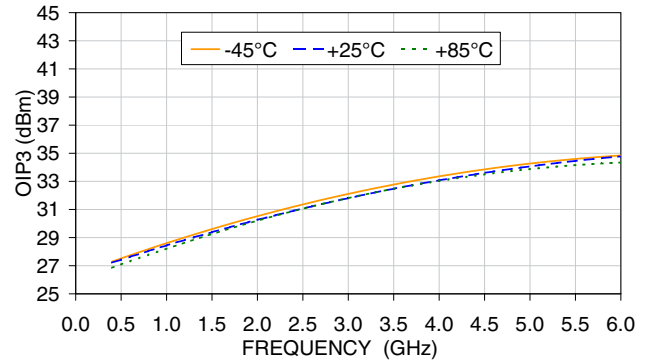


TYPICAL PERFORMANCE CURVES

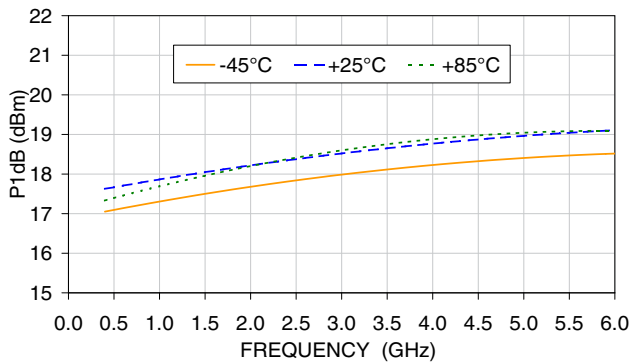
GAIN vs FREQUENCY & TEMPERATURE (1)
@ VDS=3V, IDS=30mA



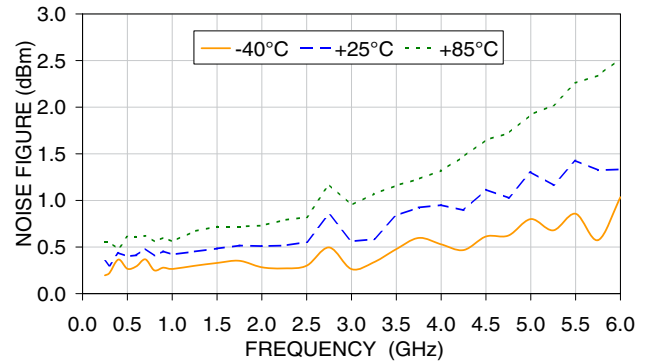
OIP3 vs FREQUENCY & TEMPERATURE (1)
@ VDS=3V, IDS=30mA



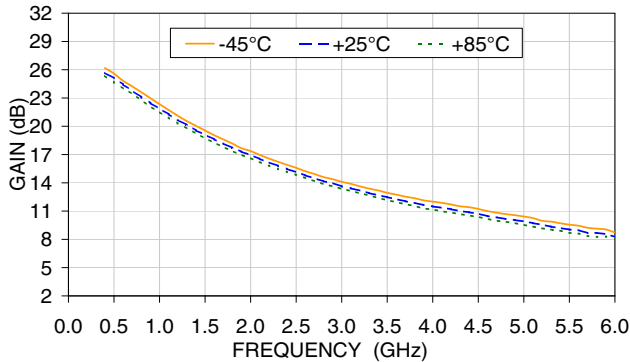
P1dB vs FREQUENCY & TEMPERATURE (1,4)
@ VDS=3V, IDS=30mA



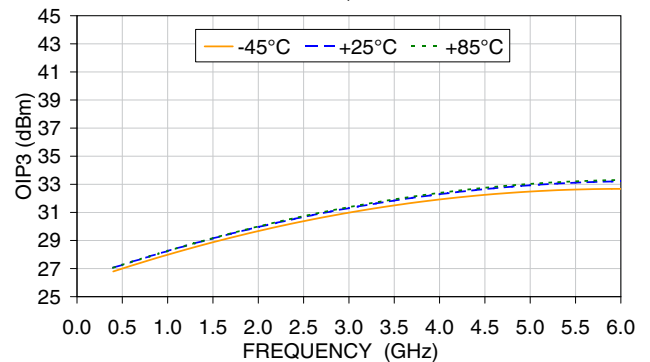
NF vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=30mA



GAIN vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=30mA



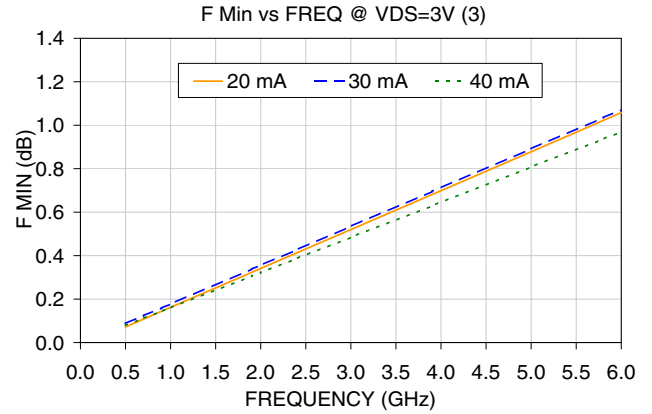
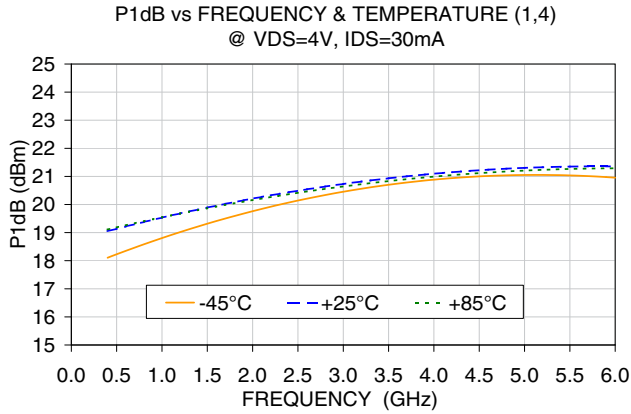
OIP3 vs FREQUENCY & TEMPERATURE
@ VDS=4V, IDS=30mA



(1) Includes test board loss, set-up and conditions per Figure 1.
 (2) Measured using HP4155B semiconductor parameter analyzer.
 (3) F Min is minimum Noise Figure.
 (4) Drain current was allowed to increase during compression measurement.



TYPICAL PERFORMANCE CURVES



- (1) Includes test board loss, set-up and conditions per Figure 1.
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- (3) F Min is minimum Noise Figure.
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REFERENCE PLANE LOCATION FOR S AND NOISE PARAMETERS (SEE DATA IN PAGES 8 & 9)

(Refer to Application Note AN-60-040)

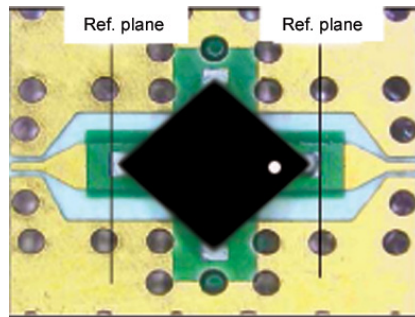


Fig 3. Reference Plane Location

Noise parameters were measured over 0.5 to 6 GHz by Modelithics® using a solid state tuner-based NP noise parameter test system available from Maury Microwave. F Min, optimum source reflection coefficient and noise resistance values are calculated values based on a set of measurements made at approximately 16 different impedances. Some data smoothing was applied to arrive at the presented data set.

S-parameters were measured by Modelithics® on an Anritsu Lightning vector network analyzer over 0.1 to 18GHz using 350um pitch RF probes from GGB industries combined with customized thru-reflect-line (TRL) calibration standards. The reference plane is at the device package leads, as shown in the picture.



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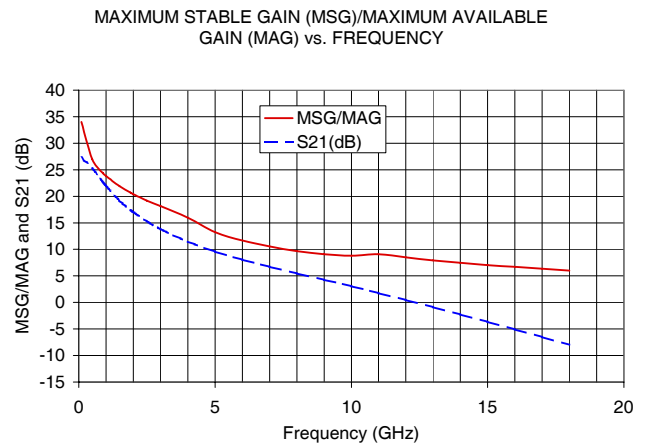
Mini-Circuits

TYPICAL S-PARAMETERS, $V_{DS}=3V$ AND $I_{DS}=30 MA$ (FIG. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	0.99	-16.36	23.19	27.31	169.5	0.009	86.4	0.60	-12.94	34.0
0.5	0.88	-73.63	18.30	25.25	132.3	0.037	52.2	0.47	-52.76	27.0
0.9	0.77	-112.16	13.45	22.57	108.1	0.05	36.6	0.35	-79.99	24.3
1.0	0.76	-120.13	12.51	21.95	103.4	0.052	34.2	0.33	-85.89	23.8
1.5	0.70	-149.97	9.11	19.19	84.2	0.059	24.0	0.25	-109.19	21.9
1.9	0.68	-167.63	7.42	17.41	72.0	0.063	19.5	0.21	-124.99	20.7
2.0	0.68	-171.42	7.09	17.02	69.3	0.065	18.2	0.20	-128.70	20.4
2.5	0.67	171.27	5.80	15.27	56.2	0.07	13.5	0.17	-146.31	19.2
3.0	0.66	156.22	4.90	13.80	44.0	0.075	8.8	0.15	-163.82	18.1
4.0	0.67	130.42	3.73	11.43	21.4	0.087	-0.3	0.13	161.15	16.0
5.0	0.68	107.77	3.02	9.59	0.0	0.099	-10.8	0.14	127.97	13.2
6.0	0.70	86.82	2.53	8.06	-20.8	0.113	-22.5	0.16	98.63	11.7
7.0	0.73	66.89	2.17	6.71	-41.4	0.125	-35.2	0.20	74.15	10.6
8.0	0.75	47.68	1.88	5.49	-61.7	0.136	-48.6	0.26	53.20	9.7
9.0	0.79	28.73	1.63	4.27	-81.9	0.145	-63.3	0.32	34.25	9.1
10.0	0.83	9.67	1.42	3.04	-102.2	0.15	-78.4	0.39	16.29	8.8
11.0	0.86	-8.89	1.23	1.77	-122.3	0.151	-94.0	0.47	-0.68	9.1
12.0	0.89	-26.76	1.06	0.47	-142.1	0.15	-109.6	0.54	-17.06	8.5
13.0	0.91	-44.42	0.91	-0.86	-162.0	0.146	-125.5	0.59	-33.39	7.9
14.0	0.93	-60.99	0.77	-2.25	178.8	0.139	-140.9	0.65	-49.07	7.5
15.0	0.94	-73.61	0.66	-3.64	163.1	0.131	-153.9	0.70	-61.42	7.0
16.0	0.96	-83.75	0.56	-5.10	149.1	0.119	-163.5	0.74	-72.07	6.7
17.0	0.96	-94.86	0.47	-6.51	134.2	0.109	-174.6	0.77	-83.99	6.4
18.0	0.95	-106.68	0.40	-7.98	118.5	0.101	174.5	0.80	-97.27	6.0

TYPICAL NOISE PARAMETERS, $V_{DS}=3V$ AND $I_{DS}=30 MA$ (FIG. 3)

Freq. (GHz)	F Min. (dB)	G _{Opt} (Magnitude)	G _{Opt} (Angle)	Rn/50	G _a Associated Gain (dB)
0.5	0.09	0.33	16.30	0.07	26.6
0.7	0.12	0.33	28.96	0.07	24.7
0.9	0.16	0.34	41.34	0.06	23.1
1.0	0.18	0.35	47.42	0.06	22.4
1.9	0.34	0.38	99.05	0.03	17.8
2.0	0.36	0.39	104.44	0.03	17.5
2.4	0.43	0.40	125.31	0.03	16.3
3.0	0.54	0.42	154.52	0.03	14.9
3.9	0.70	0.44	-166.36	0.06	13.3
5.0	0.89	0.46	-126.19	0.11	11.8
5.8	1.04	0.47	-102.25	0.16	10.7
6.0	1.07	0.47	-96.96	0.18	10.5



F Min.: Minimum Noise Figure
 G_{Opt}: Optimum Source Reflection Coefficient
 Rn: Equivalent noise resistance





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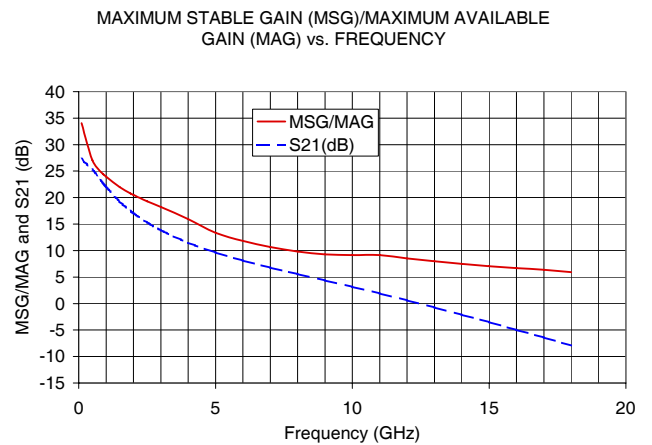
Mini-Circuits

TYPICAL S-PARAMETERS, $V_{DS}=4V$ AND $I_{DS}=30\text{ MA}$ (FIG. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	0.99	-16.62	23.16	27.30	169.5	0.009	79.4	0.61	-12.06	34.0
0.5	0.88	-73.31	18.36	25.28	132.5	0.036	52.2	0.49	-50.89	27.0
0.9	0.77	-111.77	13.51	22.61	108.3	0.049	37.1	0.36	-76.91	24.4
1.0	0.76	-119.67	12.58	21.99	103.5	0.051	33.7	0.34	-82.55	23.9
1.5	0.70	-149.65	9.17	19.25	84.3	0.058	24.1	0.25	-104.45	22.0
1.9	0.68	-167.34	7.47	17.47	72.1	0.062	19.2	0.21	-119.17	20.8
2.0	0.67	-171.13	7.14	17.07	69.3	0.063	18.4	0.20	-122.66	20.5
2.5	0.67	171.46	5.84	15.33	56.2	0.069	13.6	0.17	-139.21	19.3
3.0	0.66	156.41	4.93	13.86	44.0	0.074	9.0	0.14	-155.97	18.2
4.0	0.67	130.52	3.75	11.49	21.4	0.085	0.0	0.12	169.62	15.9
5.0	0.68	107.77	3.04	9.66	-0.1	0.098	-10.3	0.12	134.56	13.3
6.0	0.70	86.77	2.55	8.14	-20.9	0.111	-21.6	0.14	103.32	11.8
7.0	0.72	66.87	2.19	6.79	-41.6	0.123	-34.4	0.18	77.45	10.7
8.0	0.75	47.72	1.90	5.58	-61.9	0.135	-47.6	0.24	55.67	9.8
9.0	0.79	28.73	1.65	4.37	-82.2	0.144	-62.3	0.30	36.33	9.3
10.0	0.83	9.64	1.44	3.15	-102.6	0.15	-77.4	0.38	18.12	9.1
11.0	0.86	-8.92	1.24	1.89	-122.9	0.152	-93.0	0.45	0.90	9.1
12.0	0.89	-26.90	1.07	0.60	-142.8	0.151	-108.5	0.52	-15.63	8.5
13.0	0.91	-44.62	0.92	-0.73	-162.9	0.147	-124.8	0.58	-32.08	8.0
14.0	0.93	-61.40	0.78	-2.11	177.7	0.14	-140.4	0.64	-47.96	7.5
15.0	0.94	-74.24	0.67	-3.52	161.7	0.132	-153.4	0.69	-60.57	7.0
16.0	0.96	-84.49	0.56	-4.99	147.6	0.121	-163.2	0.74	-71.29	6.7
17.0	0.96	-95.82	0.48	-6.42	132.4	0.111	-174.6	0.77	-83.45	6.4
18.0	0.96	-107.81	0.40	-7.93	116.4	0.102	174.8	0.80	-96.97	5.9

TYPICAL NOISE PARAMETERS, $V_{DS}=4V$ AND $I_{DS}=30\text{ MA}$ (FIG. 3)

Freq. (GHz)	F Min. (dB)	G _{Opt} (Magnitude)	G _{Opt} (Angle)	R _n /50	G _a Associated Gain (dB)
0.5	0.09	0.37	16.12	0.08	26.6
0.7	0.12	0.37	28.50	0.07	24.6
0.9	0.16	0.37	40.63	0.06	23.0
1.0	0.18	0.37	46.59	0.06	22.3
1.9	0.34	0.39	97.42	0.03	17.8
2.0	0.35	0.39	102.75	0.03	17.4
2.4	0.42	0.40	123.43	0.03	16.3
3.0	0.53	0.41	152.52	0.03	14.9
3.9	0.69	0.43	-168.14	0.05	13.3
5.0	0.89	0.45	-127.09	0.10	11.8
5.8	1.03	0.46	-102.09	0.16	10.8
6.0	1.06	0.47	-96.48	0.18	10.6



F Min.: Minimum Noise Figure
 G_{Opt}: Optimum Source Reflection Coefficient
 R_n: Equivalent noise resistance



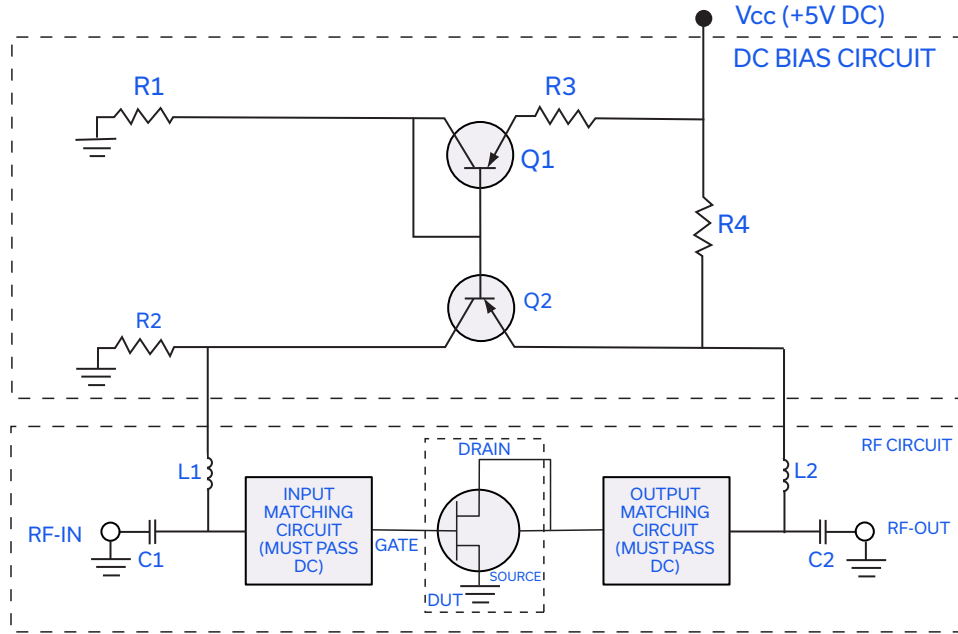


ULTRA LOW NOISE, MEDIUM CURRENT

E-PHEMT Transistor

TAV-581+

RECOMMENDED APPLICATION CIRCUIT



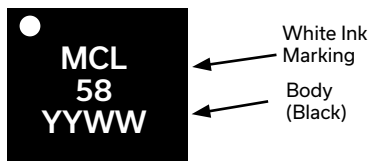
VDS, V (nom)	3	4
IDS, mA (nom)	30mA	30mA
R1	4320Ω	4320Ω
R2	4320Ω	4320Ω
R3	3570Ω	1210Ω
R4	68.1Ω	33.2Ω
Q1	MMBT3906*	MMBT3906*
Q2	MMBT3906*	MMBT3906*
C1	0.01μF	0.01μF
C2	0.01μF	0.01μF
L1**	840nH	840nH
L2**	840nH	840nH

* Fairchild Semiconductor™ part number
 ** Piconics™ part number CC45T47K240G5

OPTIMIZED AMPLIFIER CIRCUITS

For band specific, drop-in modules, and as an alternative to designing circuits, please refer to Mini-Circuits TAMP and RAMP series models which are based upon SAV/TAV E-PHEMT's and include all DC blocking, bias, matching and stabilization circuitry, without need for any external components.

PRODUCT MARKING



Marking may contain other features or characters for internal lot control





ULTRA LOW NOISE, MEDIUM CURRENT

E-PHEMT Transistor

TAV-581+

Mini-Circuits

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS [CLICK HERE](#)

Performance Data	Data Table Swept Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	FG873 Plastic low profile 3mm x 3mm, lead finish: tin/silver/nickel
Tape & Reel Standard quantities available on reel	F68 7" reels with 20, 50, 100, 200, 500,1K,2K or 3K devices
Suggested Layout for PCB Design	PL-301
Evaluation Board	TB-154+
Environmental Ratings	ENV08T2

ESD RATING

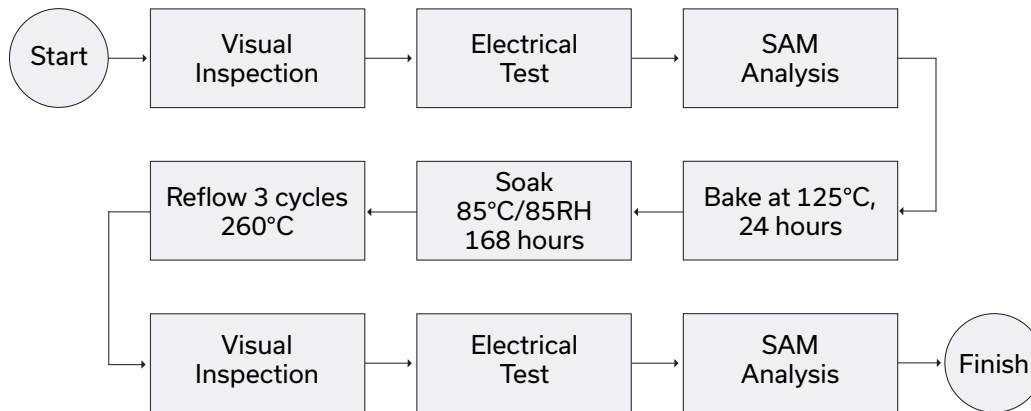
Human Body Model (HBM): Class 1A (250 V to < 500 V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (40 V) in accordance with ANSI/ESD STM 5.2 - 1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

MSL TEST FLOW CHART



- NOTES**
- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
 - B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
 - C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp



Typical Performance Data

VDS (V)	IDS (mA)				
	@ VGS=				
	0.20V	0.30V	0.40V	0.50V	0.60V
0.00	0.01	0.04	0.08	0.08	0.10
0.10	0.27	3.65	12.61	18.97	21.95
0.20	0.29	4.15	18.82	34.57	42.39
0.30	0.30	4.34	20.58	45.11	60.56
0.40	0.33	4.50	21.37	50.24	75.24
0.50	0.34	4.65	21.90	52.30	85.18
0.60	0.34	4.85	22.33	53.38	90.38
0.70	0.36	4.99	22.76	54.18	92.66
0.80	0.38	5.13	23.24	54.89	93.88
0.90	0.40	5.25	23.62	55.49	94.80
1.00	0.42	5.38	23.97	56.03	95.53
1.10	0.43	5.51	24.29	56.51	96.14
1.20	0.45	5.63	24.61	56.97	96.68
1.30	0.45	5.75	24.91	57.39	97.18
1.40	0.47	5.86	25.22	57.82	97.65
1.50	0.48	5.98	25.50	58.21	98.08
1.60	0.52	6.10	25.77	58.60	98.49
1.70	0.53	6.21	26.04	58.97	98.89
1.80	0.55	6.32	26.32	59.33	99.30
1.90	0.57	6.45	26.58	59.70	99.68
2.00	0.55	6.55	26.87	60.08	100.07
2.10	0.58	6.69	27.17	60.50	100.48
2.20	0.60	6.82	27.51	60.97	100.97
2.30	0.63	6.99	27.89	61.47	101.50
2.40	0.64	7.17	28.29	62.05	102.12
2.50	0.67	7.34	28.74	62.68	102.78
2.60	0.70	7.52	29.19	63.32	103.50
2.70	0.71	7.69	29.65	63.99	104.22
2.80	0.73	7.90	30.15	64.64	104.94
2.90	0.76	8.10	30.62	65.31	105.64
3.00	0.82	8.34	31.13	65.99	106.33
3.10	0.84	8.56	31.63	66.65	107.02
3.20	0.87	8.79	32.17	67.32	107.70
3.30	0.90	9.03	32.72	68.02	108.37
3.40	0.92	9.30	33.28	68.69	109.02
3.50	0.95	9.58	33.87	69.41	109.67
3.60	1.01	9.89	34.46	70.12	110.34
3.70	1.06	10.20	35.06	70.81	111.00
3.80	1.10	10.53	35.67	71.53	111.64
3.90	1.14	10.86	36.29	72.24	112.30
4.00	1.14	11.21	36.89	72.93	112.96
4.10	1.30	11.55	37.51	73.65	113.60
4.20	1.37	11.90	38.13	74.35	114.25
4.30	1.45	12.26	38.74	75.03	114.88
4.40	1.54	12.63	39.36	75.76	115.53
4.50	1.62	13.00	39.99	76.47	116.18
4.60	1.69	13.38	40.62	77.15	116.80
4.70	1.78	13.76	41.23	77.86	117.44
4.80	1.90	14.14	41.86	78.56	118.06
4.90	1.98	14.53	42.50	79.26	118.67
5.00	2.07	14.94	43.13	79.96	119.30

Typical Performance Data

IDS (mA)	GAIN (dB) ⁽¹⁾				OIP3 (dBm) ⁽¹⁾			
	VDS=+3V		VDS=+4V		VDS=+3V		VDS=+4V	
	0.9 GHz	2 GHz	0.9 GHz	2 GHz	0.9 GHz	2 GHz	0.9 GHz	2 GHz
10.00	19.89	15.13	19.92	15.18	19.77	22.07	19.85	22.07
15.00	21.04	15.91	21.13	15.99	22.05	23.50	22.28	24.00
30.00	22.48	16.88	22.47	16.95	28.30	30.30	27.81	30.00
60.00	23.38	17.50	23.35	17.52	32.86	33.60	33.57	35.90

IDS (mA)	Pout @ 1dB Compression ^(1,2) (dBm)				NOISE FIGURE ⁽¹⁾ (dB)			
	VDS=+3V		VDS=+4V		VDS=+3V		VDS=+4V	
	0.9 GHz	2 GHz	0.9 GHz	2 GHz	0.9 GHz	2 GHz	0.9 GHz	2 GHz
10.00	17.92	17.35	20.48	19.97	0.38	0.52	0.41	0.52
15.00	17.00	17.50	19.85	20.10	0.33	0.49	0.34	0.41
30.00	17.80	17.83	19.62	20.20	0.26	0.38	0.30	0.36
60.00	18.90	19.10	21.20	20.92	0.27	0.36	0.30	0.37

FREQ (GHz)	NF vs FREQ & TEMPERATURE ⁽¹⁾ @ VDS=3V, IDS=30mA			NF vs FREQ & TEMPERATURE ⁽¹⁾ @ VDS=4V, IDS=30mA		
	-40°C	+25°C	+85°C	-40°C	+25°C	+85°C
0.25	0.22	0.32	0.49	0.20	0.35	0.55
0.30	0.20	0.28	0.46	0.22	0.30	0.55
0.40	0.31	0.47	0.42	0.37	0.44	0.48
0.50	0.29	0.38	0.41	0.27	0.40	0.61
0.60	0.27	0.43	0.5	0.29	0.41	0.61
0.70	0.34	0.48	0.49	0.37	0.48	0.62
0.80	0.28	0.40	0.48	0.25	0.41	0.56
0.90	0.31	0.49	0.53	0.28	0.46	0.60
1.00	0.23	0.41	0.51	0.27	0.42	0.56
1.25	0.27	0.43	0.58	0.30	0.45	0.67
1.50	0.31	0.46	0.63	0.33	0.48	0.72
1.75	0.34	0.56	0.72	0.35	0.52	0.72
2.00	0.32	0.53	0.67	0.28	0.51	0.73
2.25	0.21	0.49	0.76	0.27	0.52	0.79
2.50	0.30	0.56	0.79	0.30	0.55	0.82
2.75	0.48	0.88	0.97	0.50	0.85	1.17
3.00	0.34	0.61	0.87	0.26	0.56	0.95
3.25	0.32	0.60	0.91	0.34	0.58	1.07
3.50	0.43	0.80	0.97	0.48	0.84	1.16
3.75	0.65	0.87	1.07	0.60	0.92	1.23
4.00	0.58	1.01	1.13	0.53	0.95	1.32
4.25	0.58	0.92	1.25	0.47	0.89	1.47
4.50	0.67	0.99	1.34	0.61	1.12	1.65
4.75	0.60	0.99	1.36	0.62	1.03	1.72
5.00	0.80	1.03	1.62	0.80	1.30	1.92
5.25	0.80	1.20	1.76	0.68	1.16	2.02
5.50	1.08	1.36	1.93	0.86	1.43	2.26
5.75	0.89	1.37	1.95	0.57	1.32	2.34
6.00	0.77	1.42	2.17	1.03	1.33	2.52

(1) Includes test board loss

(2) Drain current was allowed to increase during compression measurement

Typical Performance Data

FREQ (GHz)	GAIN vs FREQ & TEMPERATURE @ VDS=3V, IDS=30mA			OIP3 vs FREQ & TEMPERATURE ⁽¹⁾ @ VDS=3V, IDS=30mA			P1dB vs FREQ & TEMPERATURE ^(1,2) @ VDS=3V, IDS=30mA		
	-45°C	+25°C	+85°C	-45°C	+25°C	+85°C	-45°C	+25°C	+85°C
0.40	26.15	25.77	25.29	27.29	27.22	26.85	17.05	17.63	17.33
0.50	25.52	25.12	24.47	27.52	27.43	27.09	17.10	17.67	17.39
0.60	24.89	24.39	23.91	27.74	27.64	27.32	17.14	17.71	17.46
0.70	24.18	23.74	23.33	27.96	27.84	27.55	17.18	17.75	17.52
0.80	23.60	23.09	22.73	28.18	28.05	27.78	17.22	17.79	17.58
0.90	22.95	22.48	22.01	28.39	28.25	28.00	17.27	17.83	17.63
1.00	22.30	21.84	21.43	28.60	28.44	28.22	17.31	17.86	17.69
1.10	21.71	21.23	20.85	28.81	28.64	28.44	17.35	17.90	17.75
1.20	21.08	20.63	20.24	29.02	28.83	28.65	17.39	17.94	17.80
1.30	20.53	20.09	19.69	29.22	29.02	28.85	17.42	17.98	17.86
1.40	20.00	19.58	19.17	29.41	29.21	29.06	17.46	18.01	17.91
1.50	19.49	19.07	18.70	29.61	29.39	29.26	17.50	18.05	17.96
1.60	18.99	18.61	18.16	29.80	29.57	29.46	17.54	18.08	18.01
1.70	18.57	18.14	17.78	29.98	29.75	29.65	17.57	18.12	18.06
1.80	18.11	17.66	17.34	30.17	29.92	29.84	17.61	18.15	18.11
1.90	17.68	17.26	16.91	30.35	30.09	30.02	17.64	18.19	18.16
2.00	17.34	16.88	16.55	30.52	30.26	30.20	17.68	18.22	18.20
2.10	16.91	16.49	16.15	30.70	30.43	30.38	17.71	18.25	18.25
2.20	16.50	16.12	15.77	30.87	30.60	30.55	17.75	18.28	18.29
2.30	16.21	15.76	15.41	31.04	30.76	30.72	17.78	18.32	18.33
2.40	15.88	15.41	15.11	31.20	30.92	30.89	17.81	18.35	18.38
2.50	15.55	15.10	14.76	31.36	31.07	31.05	17.84	18.38	18.42
2.60	15.20	14.74	14.43	31.52	31.22	31.21	17.87	18.41	18.45
2.70	14.90	14.44	14.11	31.67	31.37	31.36	17.90	18.44	18.49
2.80	14.57	14.17	13.79	31.82	31.52	31.52	17.93	18.46	18.53
2.90	14.34	13.92	13.54	31.97	31.67	31.66	17.96	18.49	18.56
3.00	14.07	13.65	13.32	32.11	31.81	31.81	17.99	18.52	18.60
3.10	13.84	13.35	13.08	32.25	31.95	31.95	18.01	18.55	18.63
3.20	13.60	13.10	12.81	32.38	32.08	32.08	18.04	18.57	18.66
3.30	13.33	12.88	12.58	32.52	32.22	32.21	18.07	18.60	18.70
3.40	13.14	12.63	12.29	32.65	32.35	32.34	18.09	18.63	18.73
3.50	12.90	12.41	12.10	32.77	32.48	32.47	18.12	18.65	18.75
3.60	12.71	12.23	11.85	32.90	32.60	32.59	18.14	18.68	18.78
3.70	12.47	12.05	11.68	33.02	32.72	32.70	18.16	18.70	18.81
3.80	12.33	11.85	11.48	33.13	32.84	32.82	18.19	18.72	18.83
3.90	12.10	11.64	11.20	33.25	32.96	32.92	18.21	18.75	18.86
4.00	11.97	11.49	11.10	33.36	33.08	33.03	18.23	18.77	18.88
4.10	11.83	11.30	10.95	33.46	33.19	33.13	18.25	18.79	18.90
4.20	11.65	11.14	10.81	33.56	33.30	33.23	18.27	18.81	18.92
4.30	11.49	11.01	10.61	33.66	33.40	33.32	18.29	18.83	18.94
4.40	11.37	10.84	10.49	33.76	33.50	33.41	18.31	18.85	18.96
4.50	11.20	10.69	10.33	33.85	33.61	33.50	18.33	18.87	18.98
4.60	10.97	10.48	10.09	33.94	33.70	33.58	18.34	18.89	18.99
4.70	10.82	10.35	9.94	34.03	33.80	33.66	18.36	18.91	19.01
4.80	10.59	10.15	9.81	34.11	33.89	33.74	18.38	18.93	19.02
4.90	10.54	9.99	9.63	34.19	33.98	33.81	18.39	18.95	19.03
5.00	10.42	9.82	9.44	34.27	34.07	33.88	18.41	18.96	19.04
5.10	10.23	9.64	9.29	34.34	34.15	33.94	18.42	18.98	19.05
5.20	9.97	9.50	8.99	34.41	34.23	34.00	18.43	19.00	19.06
5.30	9.84	9.33	9.00	34.47	34.31	34.06	18.45	19.01	19.07
5.40	9.71	9.23	8.87	34.54	34.38	34.11	18.46	19.03	19.08
5.50	9.54	9.05	8.57	34.60	34.46	34.16	18.47	19.04	19.08
5.60	9.44	8.88	8.53	34.65	34.53	34.20	18.48	19.06	19.09
5.70	9.14	8.75	8.35	34.70	34.59	34.24	18.49	19.07	19.09
5.80	9.11	8.65	8.15	34.75	34.66	34.28	18.50	19.08	19.09
5.90	9.00	8.51	8.25	34.80	34.72	34.31	18.51	19.10	19.09
6.00	8.74	8.24	7.91	34.84	34.78	34.34	18.52	19.11	19.09

(1) Includes test board loss
 (2) Drain current was allowed

Typical Performance Data

FREQ (GHz)	GAIN vs FREQ & TEMPERATURE @ VDS=4V, IDS=30mA			OIP3 vs FREQ & TEMPERATURE ⁽¹⁾ @ VDS=4V, IDS=30mA			P1dB vs FREQ & TEMPERATURE ^(1,2) @ VDS=4V, IDS=30mA		
	-45°C	+25°C	+85°C	-45°C	+25°C	+85°C	-45°C	+25°C	+85°C
0.40	26.19	25.67	25.36	26.79	27.06	27.05	18.11	19.05	19.11
0.50	25.59	25.10	24.65	27.00	27.27	27.26	18.23	19.14	19.18
0.60	24.83	24.44	23.99	27.21	27.47	27.47	18.35	19.22	19.26
0.70	24.24	23.78	23.44	27.41	27.67	27.67	18.47	19.30	19.33
0.80	23.62	23.09	22.77	27.60	27.87	27.87	18.58	19.38	19.40
0.90	22.98	22.47	22.09	27.80	28.06	28.07	18.70	19.46	19.47
1.00	22.35	21.86	21.51	27.98	28.25	28.27	18.81	19.53	19.54
1.10	21.73	21.28	20.92	28.17	28.44	28.46	18.91	19.61	19.61
1.20	21.12	20.67	20.28	28.35	28.62	28.64	19.02	19.68	19.68
1.30	20.55	20.14	19.76	28.53	28.80	28.82	19.12	19.75	19.74
1.40	20.05	19.56	19.24	28.70	28.98	29.00	19.22	19.82	19.81
1.50	19.55	19.10	18.72	28.87	29.15	29.18	19.32	19.89	19.87
1.60	19.05	18.62	18.26	29.04	29.32	29.35	19.41	19.96	19.93
1.70	18.61	18.17	17.80	29.20	29.48	29.52	19.50	20.02	19.99
1.80	18.16	17.71	17.37	29.36	29.64	29.68	19.59	20.09	20.05
1.90	17.68	17.30	16.96	29.52	29.80	29.85	19.68	20.15	20.10
2.00	17.37	16.95	16.62	29.67	29.96	30.00	19.76	20.21	20.16
2.10	16.96	16.53	16.20	29.82	30.11	30.16	19.84	20.27	20.21
2.20	16.58	16.17	15.83	29.96	30.25	30.31	19.92	20.33	20.27
2.30	16.24	15.81	15.47	30.10	30.40	30.45	20.00	20.38	20.32
2.40	15.91	15.47	15.15	30.24	30.54	30.60	20.07	20.44	20.37
2.50	15.59	15.13	14.84	30.37	30.67	30.74	20.14	20.49	20.42
2.60	15.23	14.79	14.49	30.50	30.81	30.87	20.21	20.54	20.47
2.70	14.94	14.48	14.18	30.63	30.94	31.00	20.27	20.59	20.51
2.80	14.61	14.16	13.85	30.75	31.06	31.13	20.34	20.64	20.56
2.90	14.39	13.98	13.63	30.87	31.18	31.26	20.40	20.69	20.60
3.00	14.11	13.62	13.35	30.98	31.30	31.38	20.45	20.73	20.64
3.10	13.89	13.42	13.14	31.09	31.42	31.49	20.51	20.77	20.68
3.20	13.63	13.17	12.88	31.20	31.53	31.61	20.56	20.82	20.72
3.30	13.39	12.91	12.67	31.30	31.64	31.72	20.61	20.86	20.76
3.40	13.19	12.68	12.39	31.40	31.74	31.82	20.66	20.90	20.80
3.50	12.94	12.48	12.16	31.50	31.84	31.93	20.70	20.93	20.84
3.60	12.75	12.27	11.94	31.59	31.94	32.03	20.74	20.97	20.87
3.70	12.53	12.04	11.73	31.68	32.03	32.12	20.78	21.00	20.90
3.80	12.36	11.88	11.54	31.76	32.13	32.21	20.82	21.04	20.93
3.90	12.14	11.64	11.27	31.84	32.21	32.30	20.85	21.07	20.96
4.00	12.00	11.49	11.17	31.92	32.30	32.38	20.88	21.10	20.99
4.10	11.88	11.35	10.98	31.99	32.37	32.47	20.91	21.12	21.02
4.20	11.70	11.20	10.85	32.06	32.45	32.54	20.94	21.15	21.05
4.30	11.51	11.00	10.68	32.13	32.52	32.62	20.96	21.17	21.07
4.40	11.41	10.87	10.53	32.19	32.59	32.69	20.98	21.20	21.10
4.50	11.23	10.72	10.38	32.25	32.66	32.75	21.00	21.22	21.12
4.60	11.00	10.47	10.17	32.30	32.72	32.81	21.02	21.24	21.14
4.70	10.83	10.34	9.98	32.35	32.78	32.87	21.03	21.26	21.16
4.80	10.68	10.16	9.87	32.40	32.83	32.93	21.04	21.27	21.18
4.90	10.57	10.05	9.73	32.45	32.88	32.98	21.05	21.29	21.19
5.00	10.42	9.91	9.54	32.49	32.93	33.03	21.05	21.30	21.21
5.10	10.26	9.72	9.36	32.52	32.98	33.07	21.05	21.32	21.22
5.20	9.97	9.55	9.17	32.55	33.02	33.11	21.05	21.33	21.23
5.30	9.88	9.34	9.04	32.58	33.05	33.15	21.05	21.34	21.25
5.40	9.71	9.20	8.93	32.61	33.09	33.18	21.04	21.34	21.26
5.50	9.56	9.04	8.69	32.63	33.12	33.21	21.04	21.35	21.27
5.60	9.45	8.98	8.63	32.64	33.14	33.24	21.02	21.35	21.27
5.70	9.23	8.67	8.36	32.66	33.17	33.26	21.01	21.36	21.28
5.80	9.13	8.69	8.26	32.67	33.18	33.28	20.99	21.36	21.28
5.90	9.05	8.56	8.31	32.67	33.20	33.29	20.98	21.36	21.29
6.00	8.73	8.27	8.00	32.68	33.21	33.31	20.95	21.36	21.29

(1) Includes test board loss

(2) Drain current was allowed

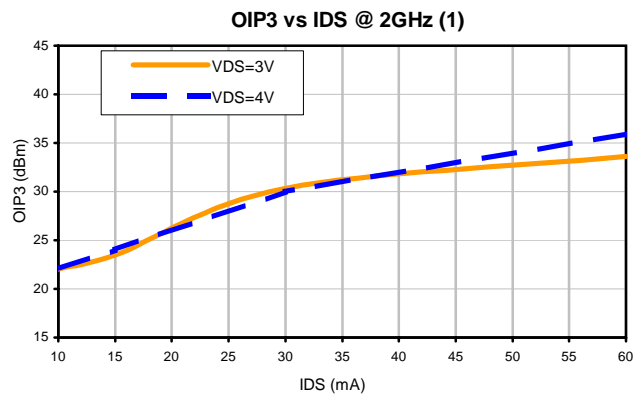
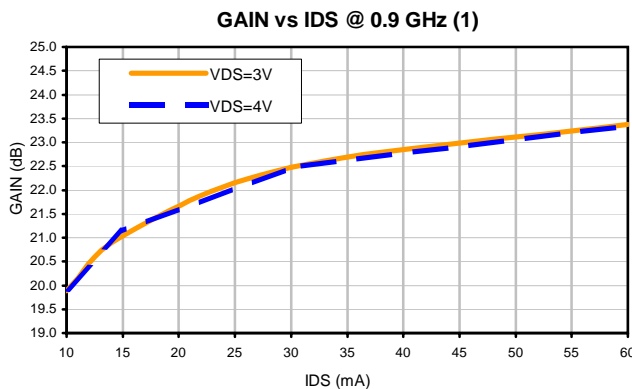
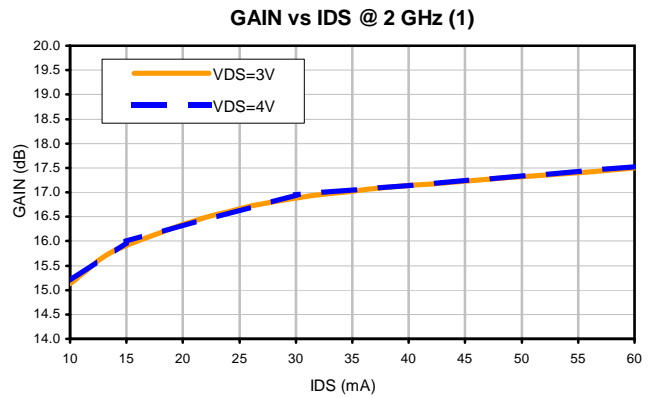
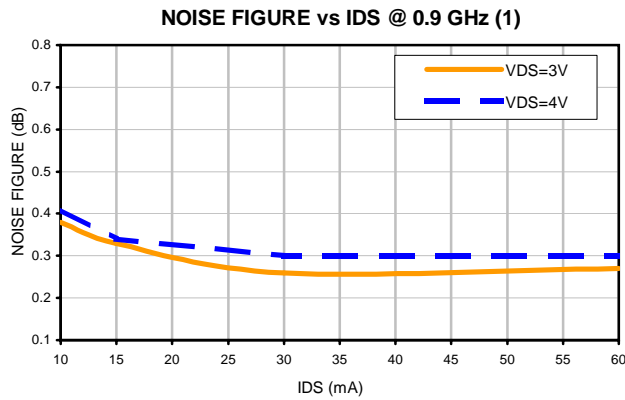
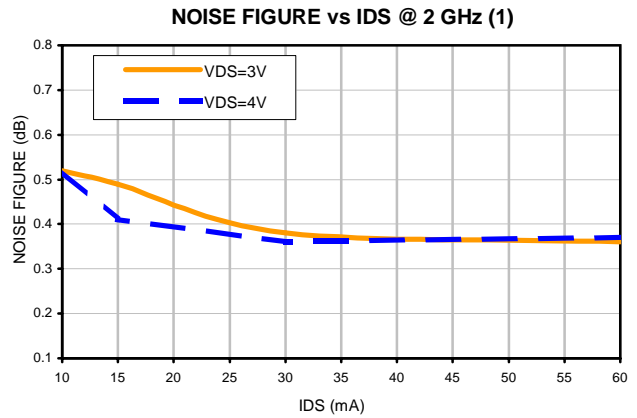
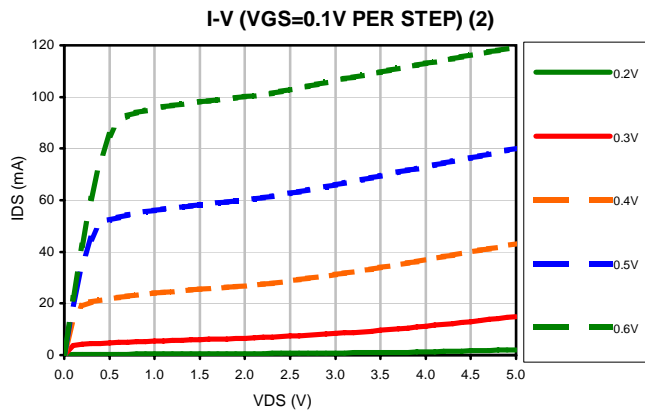
Typical Performance Data

IDS (mA)	F _{MIN} (dB) (1)					
	VDS=+2V		VDS=+3V		VDS=+4V	
	0.9 GHz	2 GHz	0.9 GHz	2 GHz	0.9 GHz	2 GHz
10.00	0.170	0.381	0.171	0.381	0.148	0.334
15.00	0.160	0.362	0.152	0.340		
20.00	0.165	0.365	0.144	0.341	0.157	0.352
30.00	0.169	0.372	0.159	0.356		
40.00	0.147	0.331	0.144	0.322	0.149	0.333
60.00	0.150	0.341	0.152	0.341	0.165	0.369
80.00	0.157	0.356	0.168	0.379		

FREQUENCY (GHz)	F _{MIN} (dB) (1)		
	VDS=3V		
	20 mA	30 mA	40 mA
0.50	0.07	0.09	0.08
0.70	0.11	0.12	0.11
0.90	0.14	0.16	0.14
1.00	0.16	0.18	0.16
1.90	0.32	0.34	0.31
2.00	0.34	0.36	0.32
2.40	0.41	0.43	0.39
3.00	0.52	0.54	0.48
3.90	0.68	0.70	0.63
5.00	0.88	0.89	0.81
5.80	1.02	1.04	0.94
6.00	1.06	1.07	0.97

(1) F MIN is minimum Noise Figure

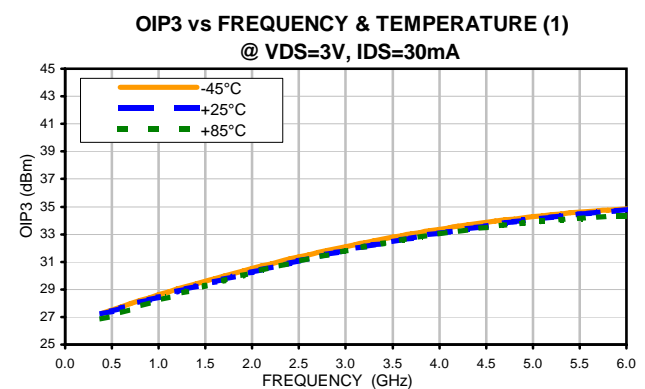
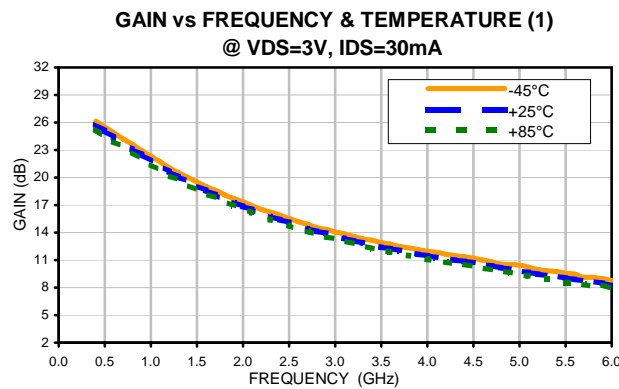
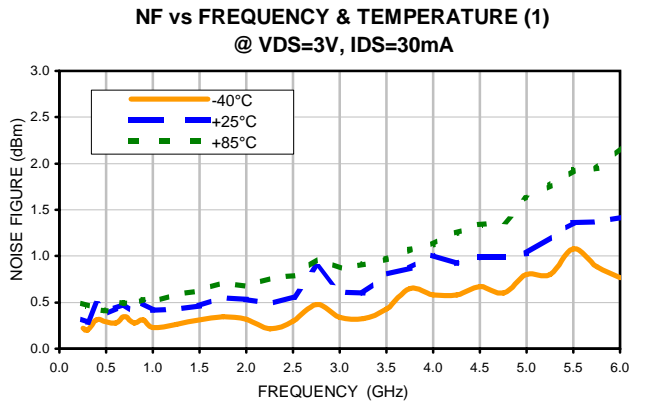
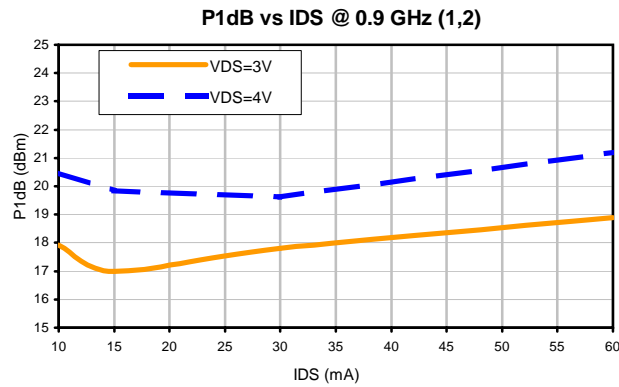
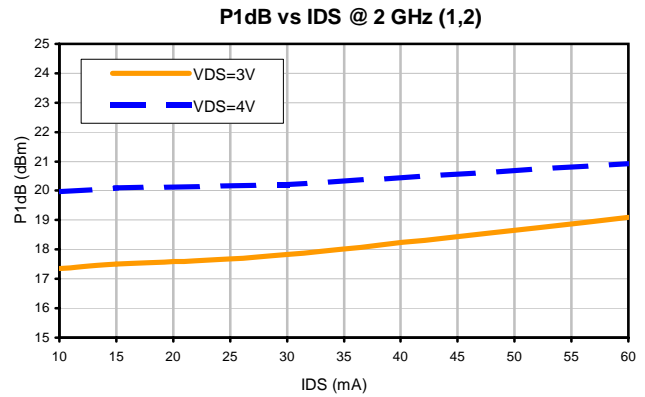
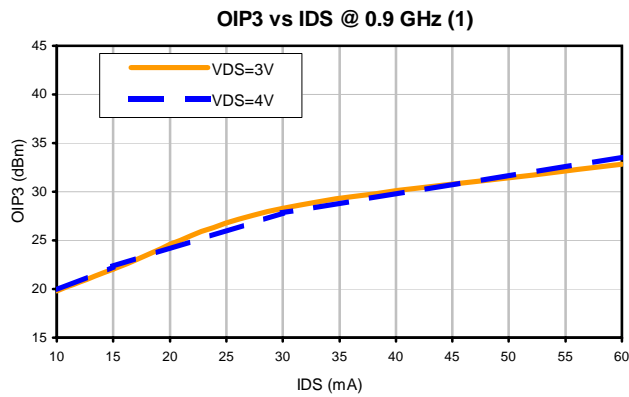
Typical Performance Curves



(1) Includes test board loss

(2) Measured using HP4155B semiconductor parameter analyzer

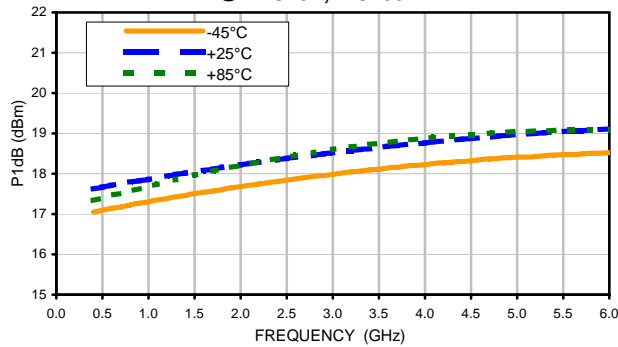
Typical Performance Curves



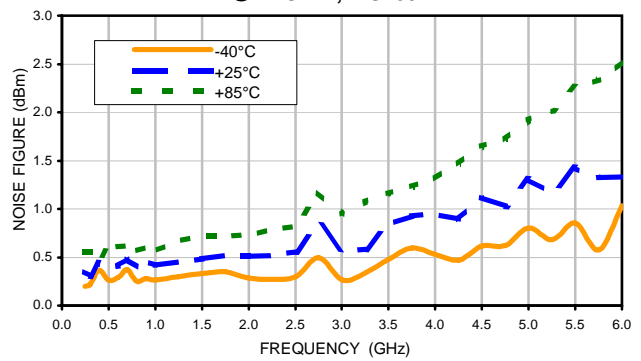
- (1) Includes test board loss
- (2) Drain current was allowed to increase during compression measurement

Typical Performance Curves

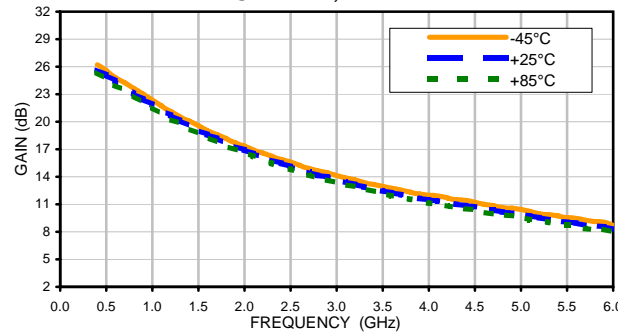
P1dB vs FREQUENCY & TEMPERATURE (1,2)
@ VDS=3V, IDS=30mA



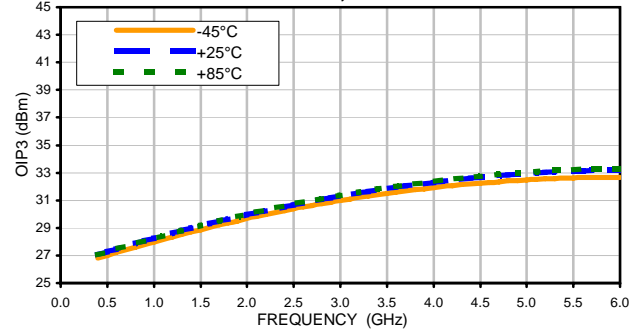
NF vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=30mA



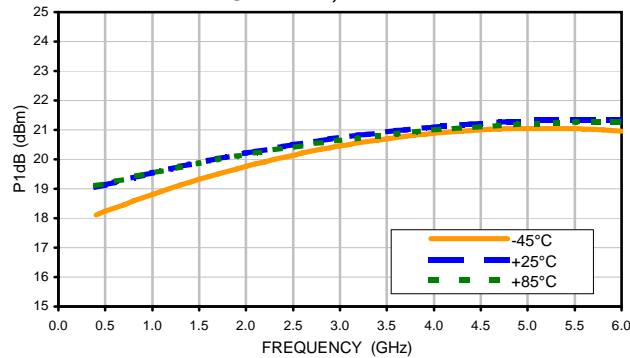
GAIN vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=30mA



OIP3 vs FREQUENCY & TEMPERATURE
@ VDS=4V, IDS=30mA



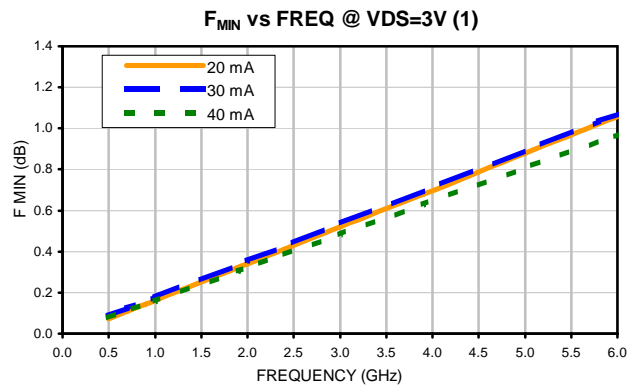
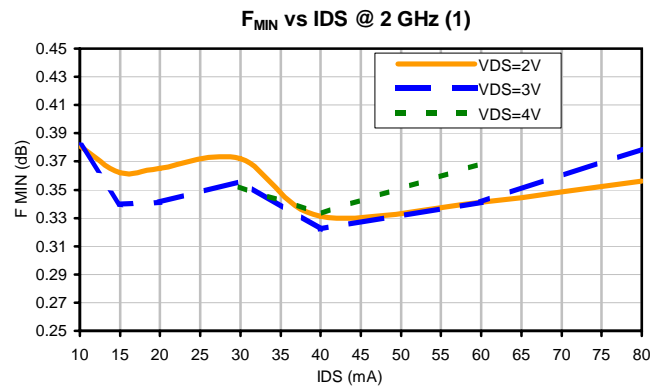
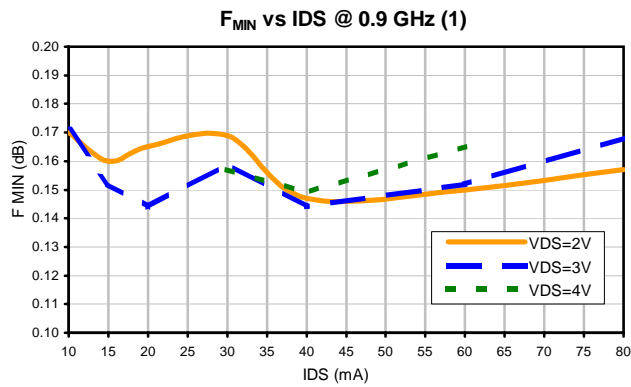
P1dB vs FREQUENCY & TEMPERATURE (1,2)
@ VDS=4V, IDS=30mA



(1) Includes test board loss

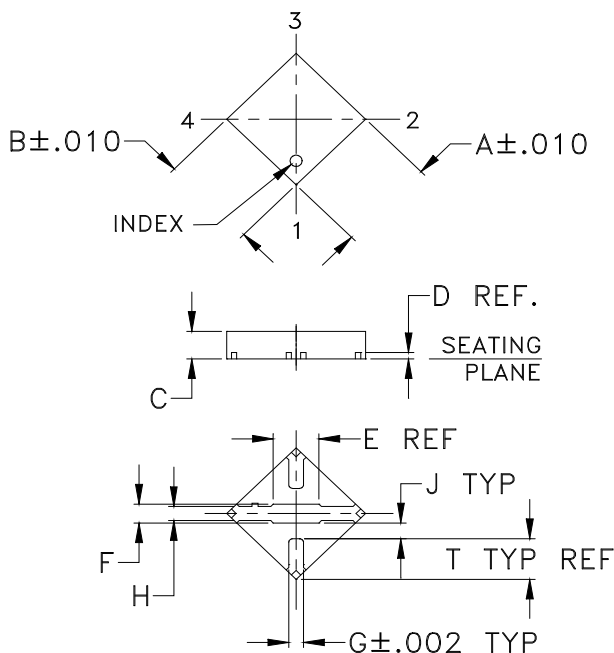
(2) Drain current was allowed to increase during compression measurement

Typical Performance Curves

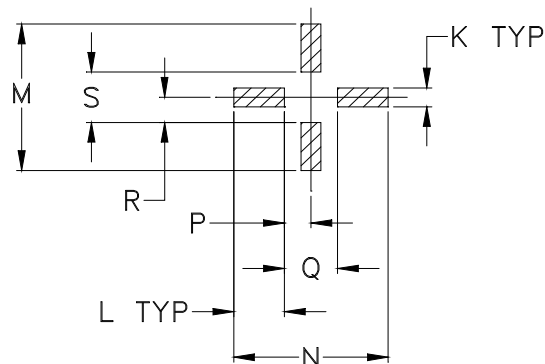


(1) F_{MIN} is minimum Noise Figure

Outline Dimensions



PCB Land Pattern



Suggested Layout,
Tolerance to be within $\pm .002$

CASE #	A	B	C	D	E	F	G	H	J	K	L	M	N	P
FG873	.118 (3.00)	.118 (3.00)	.035 (0.89)	.008 (0.20)	.07 (1.78)	.024 (0.60)	.017 (0.43)	.018 (0.46)	.021 (0.52)	.024 (0.61)	.061 (1.55)	.186 (4.72)	.186 (4.72)	.032 (0.81)

CASE #	Q	R	S	T	WT. GRAM
FG873	.064 (1.63)	.032 (0.81)	.064 (1.63)	.050 (1.27)	.02

Dimensions are in inches (mm). Tolerances: 2 Pl. $\pm .01$; 3Pl. $\pm .004$

Notes:

- Case material: Plastic.
- Termination finish:
For RoHS Case Styles: Tin-Silver alloy plate over Nickel barrier or Matte-Tin per Data Sheet.
All models, (+) suffix.
For RoHS-5 Case Styles: Tin-Lead plate. All models, no (+) suffix.



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For detailed performance specs & shopping online see Mini-Circuits web site

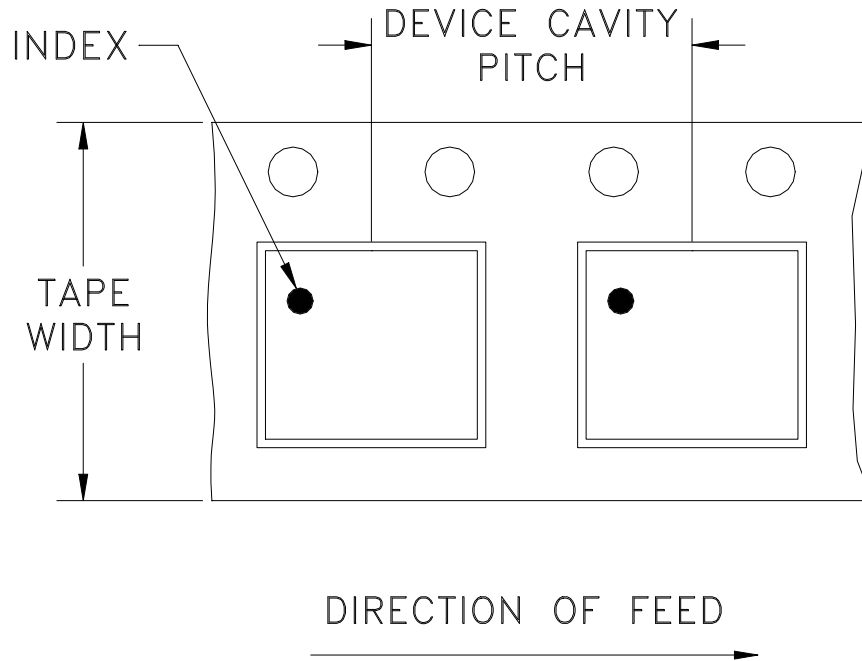


The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

RF/IF MICROWAVE COMPONENTS

Tape & Reel Packaging TR-F68

DEVICE ORIENTATION IN T&R



Tape Width, mm	Device Cavity Pitch, mm	Reel Size, inches	Devices per Reel see note	
12	8	7	Small quantity standard	20
				50
				100
				200
				500
		7	Standard	1000
		13	Standard	2000
				3000
				4000

Mini-Circuits carrier tape materials provide protection from ESD (Electro-Static Discharge) during handling and transportation. Tapes are static dissipative and comply with industry standards EIA-481/EIA-541.

Go to: www.minicircuits.com/pages/pdfs/tape.pdf

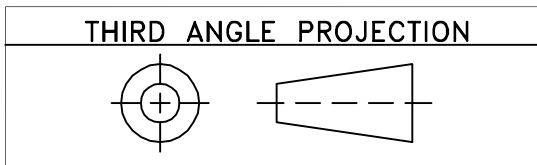


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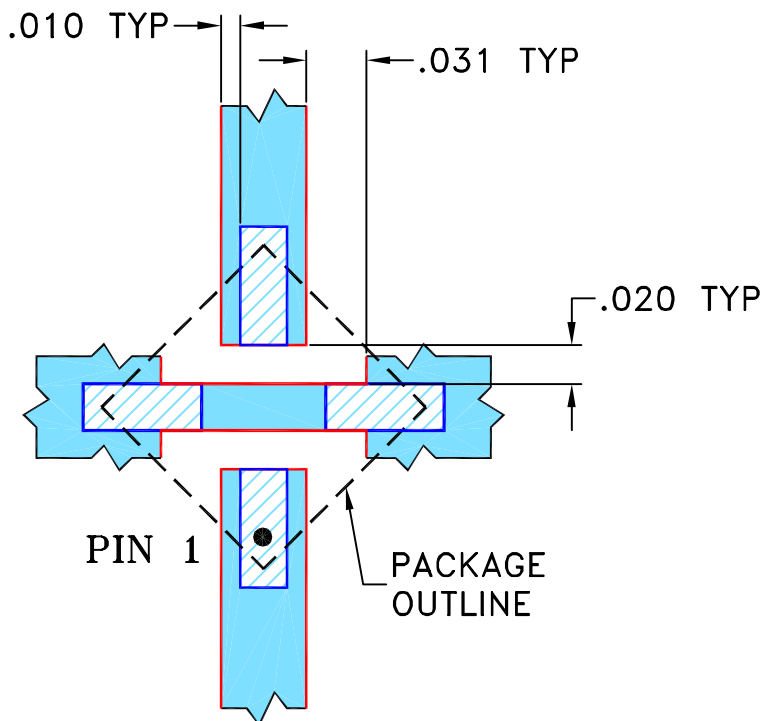
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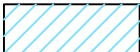


REVISIONS					
REV OR	ECN No.	DESCRIPTION	DATE	DR	AUTH
	M121883	NEW RELEASE	03/10/09	AV	TH

SUGGESTED MOUNTING CONFIGURATION FOR FG873 CASE STYLE, "04AM01" PIN CODE



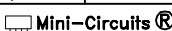
NOTES:

1. TRACE WIDTH IS SHOWN FOR REFERENCE ONLY. ACTUAL LINE WIDTH IS A FUNCTION OF SPECIFIC MATCHING CIRCUIT.
2. BOTTOM SIDE OF THE PCB IS CONTINUOUS GROUND PLANE.
3.  DENOTES PCB COPPER LAYOUT WITH SMOBC (SOLDER MASK OVER BARE COPPER);
 DENOTES COPPER LAND PATTERN FREE OF SOLDER MASK.

UNLESS OTHERWISE SPECIFIED	INITIALS	DATE
DIMENSIONS ARE IN INCHES	DRAWN AV	03/06/09
TOLERANCES ON:	CHECKED IL	03/10/09
2 PL DECIMALS ±	APPROVED TH	03/10/09
3 PL DECIMALS ± .005		
ANGLES ±		
FRACTIONS ±		

 **Mini-Circuits®** 13 Neptune Avenue
Brooklyn NY 11235

PL, 04AM01, FG873, TAV

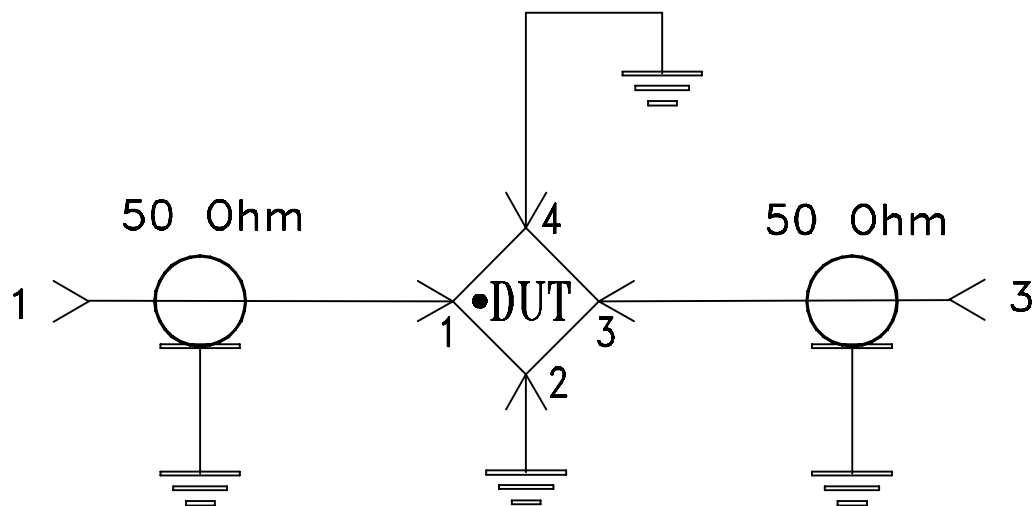
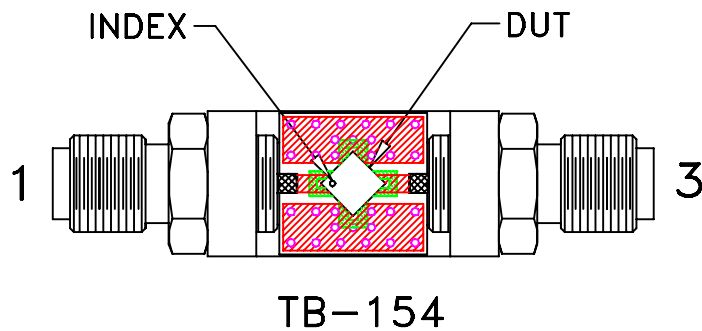
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ASHEETA1.DWG REV:A DATE:01/12/95

SIZE A	CODE IDENT 15542	DRAWING NO: 98-PL-301	REV: OR
FILE: 98PL301	SCALE: 10:1	SHEET: 1 OF 1	

Characterization Test Board


For Pins Connections refer to Data Sheet of the DUT



Schematic Diagram

Notes:

1. SMA Female connectors.
2. PCB Material: Rogers R04350 or equivalent,
Dielectric Constant=3.5, Thickness=.020 inch.

 Mini-Circuits®

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -45° to 85° C or -55° to 105° C or -40° to 105° C or -40° to 95° C Ambient Environment	Individual Model Data Sheet
Storage Temperature	-55° to 100° C or -65° to 150° Ambient Environment	Individual Model Data Sheet
HTOL	1000 hours at 125°C	MIL-STD-883, Method 1005, Condition B
Thermal Shock	-55° to 100°C, 100 cycles	MIL-STD-202, Method 107, Condition A-3, except +100°C
Mechanical Shock	1.5Kg, 0.5 ms, 5 shock pulses, Y1 direction only	MIL-STD-883, Method 2002, Condition B, except Y1 direction only
Vibration (Variable Frequency)	50g peak	MIL-STD-883, Method 2007, Condition B
Autoclave	15 psig, 100% RH, 121°C, 96 hours	JESD22-A102, Condition C
HAST	130°C, 85% RH, 96 hours	JESD22-A110
Solderability	10X Magnification	J-STD-002, Para 4.2.5, Test S, 95% Coverage
Solder Reflow Heat	Sn-Pb Eutetic Process: 240°C peak Pb-Free Process: 260°C peak	J-STD-020, Table 4-1, 4-2 and 5-2; Figure 5-1
Moisture Sensitivity: Level 1	Bake at 125°C for 24 hours Soak at 85°C/85% RH for 168 hours, Reflow 3 cycles at 260°C peak	J-STD-020

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Marking Resistance to Solvents	Isopropyl alcohol + mineral spirits at 25°C; terpene defluxer at 25°C; distilled water + proylene glycol monomethyl ether + monoethanolamine at 63°C to 70°C	MIL-STD-202, Method 215